



## Standard Recovery Diodes (Hockey PUK Version), 1200 A



DO-200AB (B-PUK)

### FEATURES

- Wide current range
- High voltage ratings up to 4500 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AB (B-PUK)
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS  
COMPLIANT

### TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

| PRODUCT SUMMARY       |                  |
|-----------------------|------------------|
| $I_{F(AV)}$           | 1200 A           |
| Package               | DO-200AB (B-PUK) |
| Circuit configuration | Single diode     |

| MAJOR RATINGS AND CHARACTERISTICS |                 |              |              |                   |
|-----------------------------------|-----------------|--------------|--------------|-------------------|
| PARAMETER                         | TEST CONDITIONS | SD800C..L    |              | UNITS             |
|                                   |                 | 24 to 36     | 40 to 45     |                   |
| $I_{F(AV)}$                       |                 | 1180         | 1065         | A                 |
|                                   | $T_{hs}$        | 55           | 55           | °C                |
| $I_{F(RMS)}$                      |                 | 2280         | 2040         | A                 |
|                                   | $T_{hs}$        | 25           | 25           | °C                |
| $I_{FSM}$                         | 50 Hz           | 13 600       | 12 200       | A                 |
|                                   | 60 Hz           | 14 240       | 12 800       |                   |
| $I^2t$                            | 50 Hz           | 925          | 745          | kA <sup>2</sup> s |
|                                   | 60 Hz           | 845          | 680          |                   |
| $V_{RRM}$                         | Range           | 2400 to 3600 | 4000 to 4500 | V                 |
| $T_J$                             |                 | -40 to 150   | -40 to 150   | °C                |

### ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS |              |  |  |  |
|-----------------|--------------|--|--|--|
| TYPE NUMBER     | VOLTAGE CODE | $V_{RRM}$ , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE<br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE<br>V | $I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM<br>mA |
| VS-SD800C..L    | 24           | 2400   | 2500   | 50   |
|                 | 30           | 3000   | 3100   |  |
|                 | 36           | 3600   | 3700   |  |
|                 | 40           | 4000   | 4100   |  |
|                 | 45           | 4500   | 4600   |  |



| FORWARD CONDUCTION  |               |  |                           |   |            |                    |                   |
|---|---------------|--|---------------------------|---|------------|--------------------|-------------------|
| PARAMETER   | SYMBOL        | TEST CONDITIONS  |                           | SD800C..L   |            | UNITS              |                   |
|   |               |  |                           | 24 to 36  | 40 to 45   |                    |                   |
| Maximum average forward current at heatsink temperature       | $I_{F(AV)}$   | 180° conduction, half sine wave<br>Double side (single side) cooled                      |                           | 1180 (550)  | 1065 (490) | A                  |                   |
|   |               |  |                           | 55 (85)   | 55 (85)    | °C                 |                   |
| Maximum RMS forward current                                   | $I_{F(RMS)}$  | 25 °C heatsink temperature double side cooled  |                           | 2280  | 2040       |                    |                   |
| Maximum peak, one-cycle forward, non-repetitive surge current | $I_{FSM}$     | t = 10 ms  | No voltage reappplied     | Sinusoidal half wave, initial $T_J = T_J$ maximum | 13 600     | 12 200             | A                 |
|   |               | t = 8.3 ms   |                           |   | 14 240     | 12 800             |                   |
|   |               | t = 10 ms  | 50 % $V_{RRM}$ reappplied |   | 11 440     | 10 250             |                   |
|   |               | t = 8.3 ms   |                           |   | 11 980     | 10 750             |                   |
| Maximum $I^2t$ for fusing                                     | $I^2t$        | t = 10 ms  | No voltage reappplied     |   | 925        | 745                | kA <sup>2</sup> s |
|   |               | t = 8.3 ms   |                           |   | 845        | 680                |                   |
|   |               | t = 10 ms  | 50 % $V_{RRM}$ reappplied |   | 654        | 526                |                   |
|   |               | t = 8.3 ms   |                           |   | 597        | 480                |                   |
| Maximum $I^2\sqrt{t}$ for fusing                              | $I^2\sqrt{t}$ | t = 0.1 to 10 ms, no voltage reappplied  |                           | 9250  | 7450       | kA <sup>2</sup> √s |                   |
| Low level value of threshold voltage                          | $V_{F(TO)1}$  | $(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum |                           | 0.90  | 1.06       | V                  |                   |
| High level value of threshold voltage                         | $V_{F(TO)2}$  | $(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum                                       |                           | 1.10  | 1.18       |                    |                   |
| Low level value of forward slope resistance                   | $r_{f1}$      | $(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum |                           | 0.38  | 0.44       | mΩ                 |                   |
| High level value of forward slope resistance                  | $r_{f2}$      | $(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum                                       |                           | 0.34  | 0.41       |                    |                   |
| Maximum forward voltage drop                                  | $V_{FM}$      | $I_{pk} = 2000$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave                    |                           | 1.66  | 1.95       | V                  |                   |

| THERMAL AND MECHANICAL SPECIFICATIONS            |              |   |                  |        |
|--|--------------|---|------------------|--------|
| PARAMETER  | SYMBOL       | TEST CONDITIONS                               | VALUES           | UNITS  |
| Maximum junction operating temperature range     | $T_J$        |   | - 40 to 150      | °C     |
| Maximum storage temperature range                | $T_{Stg}$    |   | - 55 to 200      |        |
| Maximum thermal resistance, junction to heatsink | $R_{thJ-hs}$ | DC operation single side cooled               | 0.073            | K/W    |
|  |              | DC operation double side cooled               | 0.031            |        |
| Mounting force, ± 10 %                           |              |   | 14 700 (1500)    | N (kg) |
| Approximate weight                               |              |   | 255              | g      |
| Case style                                       |              | See dimensions - link at the end of datasheet | DO-200AB (B-PUK) |        |

| $\Delta R_{thJ-hs}$ CONDUCTION |                       |             |                        |             |                     |       |
|--------------------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|
| CONDUCTION ANGLE               | SINUSOIDAL CONDUCTION |             | RECTANGULAR CONDUCTION |             | TEST CONDITIONS     | UNITS |
|                                | SINGLE SIDE           | DOUBLE SIDE | SINGLE SIDE            | DOUBLE SIDE |                     |       |
| 180°                           | 0.009                 | 0.009       | 0.006                  | 0.006       | $T_J = T_J$ maximum | K/W   |
| 120°                           | 0.011                 | 0.011       | 0.011                  | 0.011       |                     |       |
| 90°                            | 0.014                 | 0.014       | 0.015                  | 0.015       |                     |       |
| 60°                            | 0.020                 | 0.020       | 0.021                  | 0.021       |                     |       |
| 30°                            | 0.036                 | 0.036       | 0.036                  | 0.036       |                     |       |

**Note**

- The table above shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC

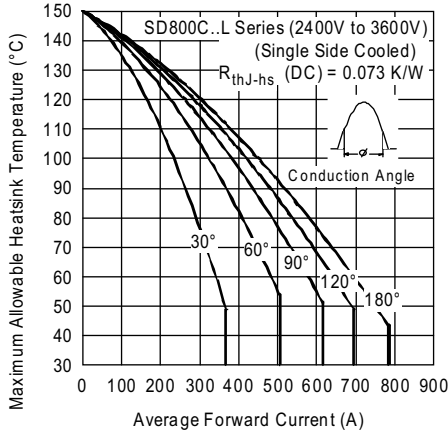


Fig. 1 - Current Ratings Characteristics

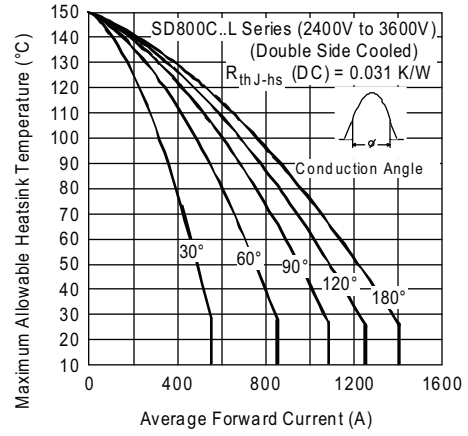


Fig. 4 - Current Ratings Characteristics

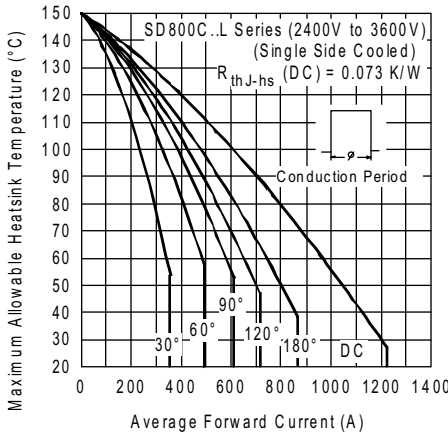


Fig. 2 - Current Ratings Characteristics

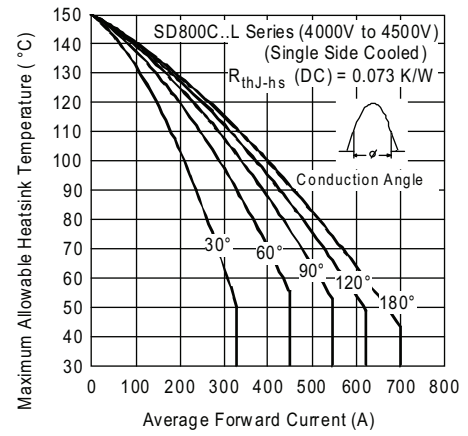


Fig. 5 - Current Ratings Characteristics

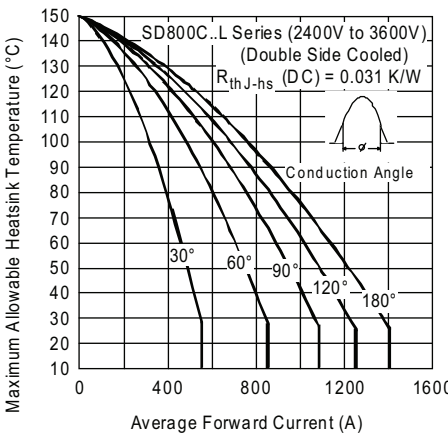


Fig. 3 - Current Ratings Characteristics

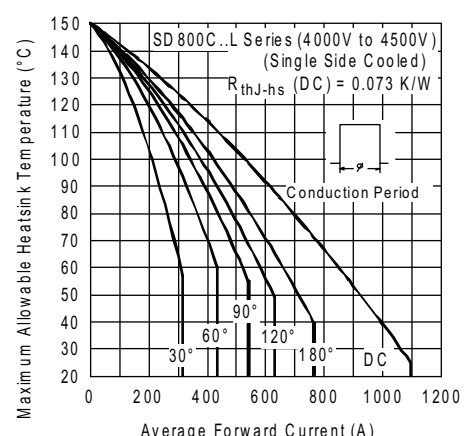


Fig. 6 - Current Ratings Characteristics

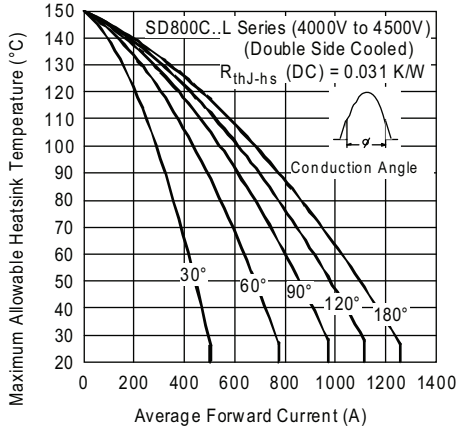


Fig. 7 - Current Ratings Characteristics

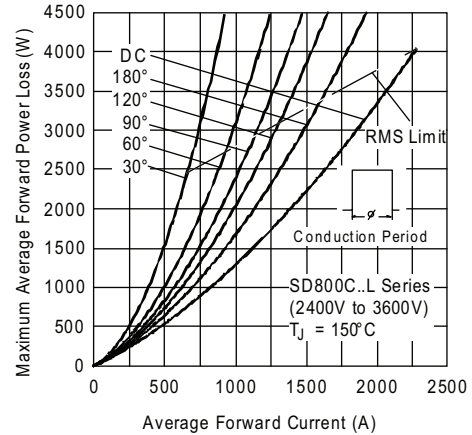


Fig. 10 - Forward Power Loss Characteristics

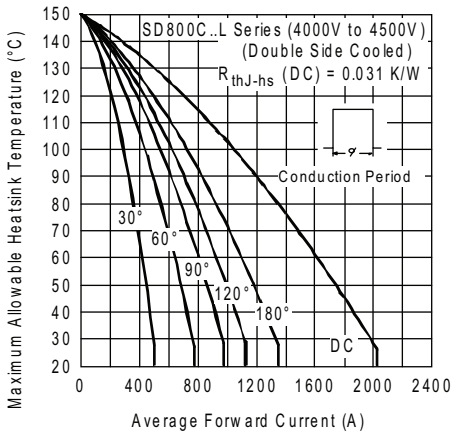


Fig. 8 - Current Ratings Characteristics

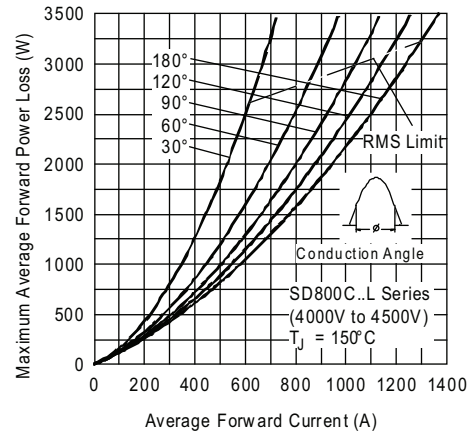


Fig. 11 - Forward Power Loss Characteristics

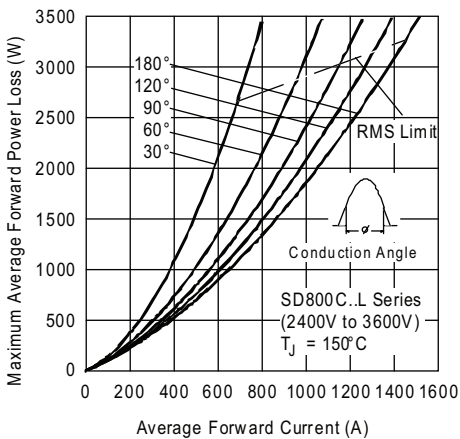


Fig. 9 - Forward Power Loss Characteristics

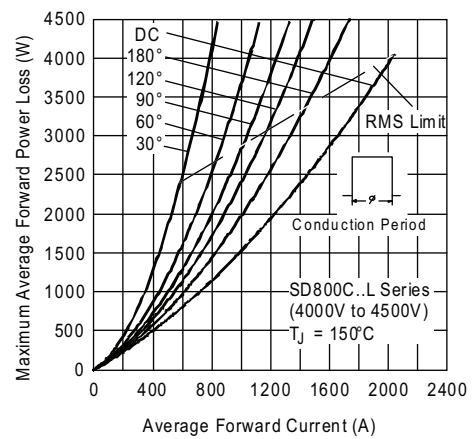


Fig. 12 - Forward Power Loss Characteristics

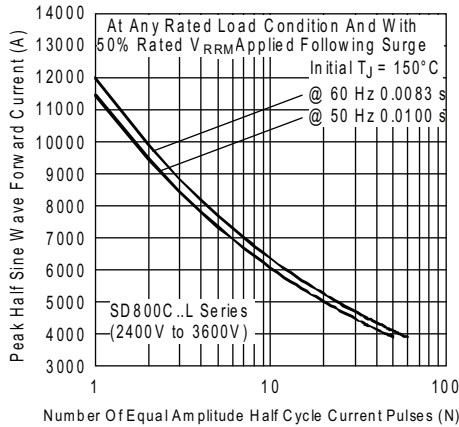


Fig. 13 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

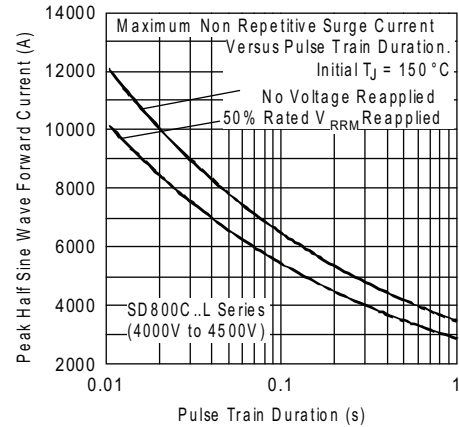


Fig. 16 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

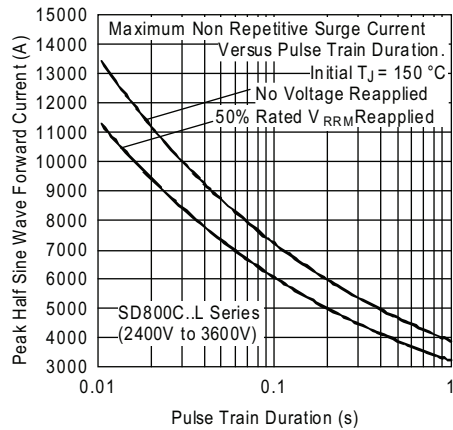


Fig. 14 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

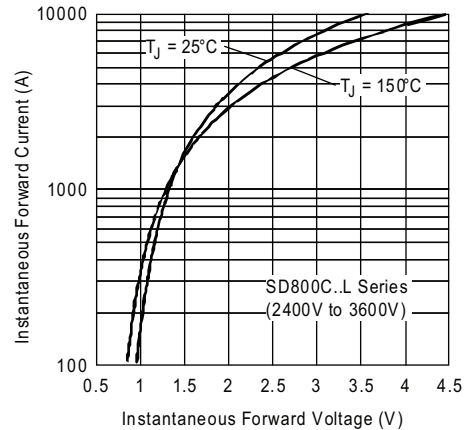


Fig. 17 - Forward Voltage Drop Characteristics

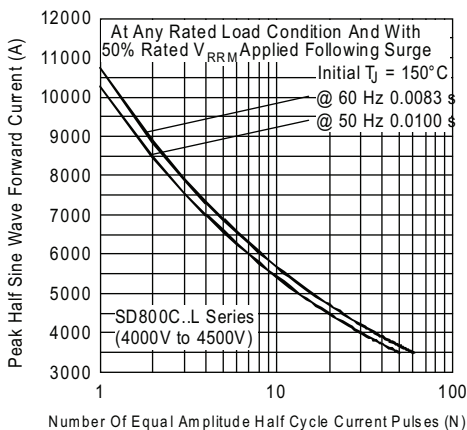


Fig. 15 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

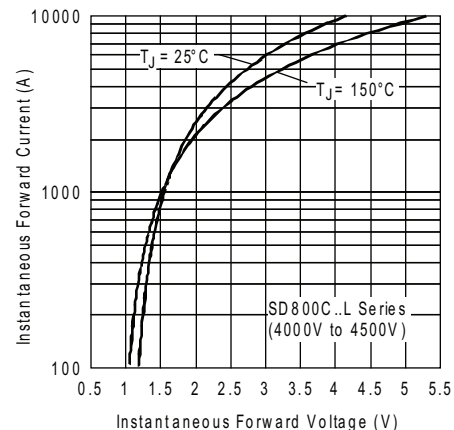


Fig. 18 - Forward Voltage Drop Characteristics

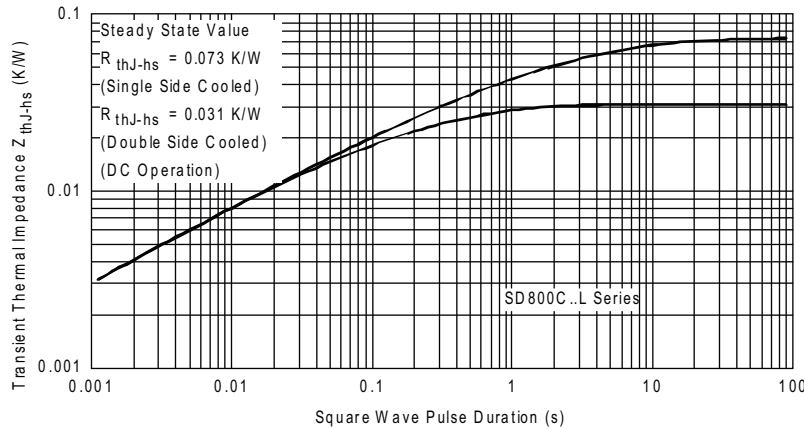


Fig. 19 - Thermal Impedance  $Z_{thj-hs}$  Characteristics

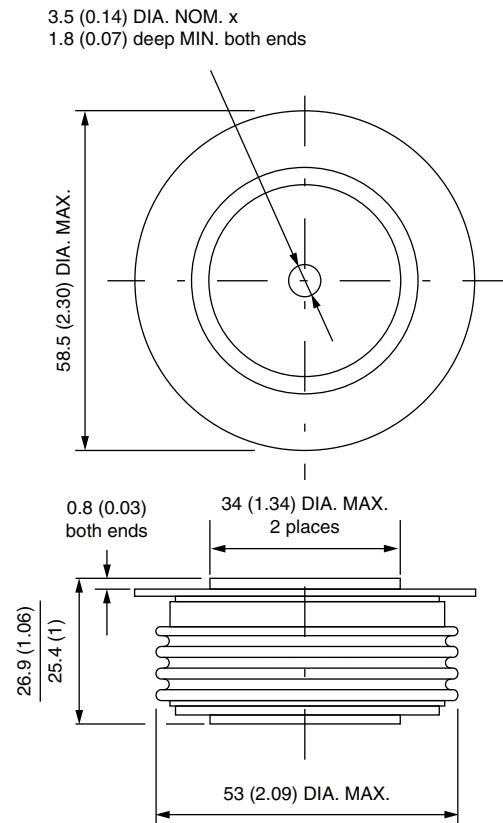
**ORDERING INFORMATION TABLE**

|             |            |           |                               |          |          |  |          |
|-------------|------------|-----------|-------------------------------|----------|----------|--|----------|
| Device code | <b>VS-</b> | <b>SD</b> | <b>80</b>                     | <b>0</b> | <b>C</b> | <b>45</b>  | <b>L</b> |
|             | ①          | ②         | ③                             | ④        | ⑤        | ⑥  |          |
|             | <b>1</b>   | -         | Vishay Semiconductors product | <b>2</b> | -        | Diode  |          |
|             | <b>3</b>   | -         | Essential part number         | <b>4</b> | -        | 0 = Standard recovery                                      |          |
|             | <b>5</b>   | -         | C = Ceramic PUK               | <b>6</b> | -        | Voltage code x 100 = $V_{RRM}$ (see Voltage Ratings table) |          |
|             | <b>6</b>   | -         | L = PUK case DO-200AB (B-PUK) |          |          |  |          |

| LINKS TO RELATED DOCUMENTS |  |
|----------------------------|--|
| Dimensions                 | <a href="http://www.vishay.com/doc?95246">www.vishay.com/doc?95246</a> |

## DO-200AB (B-PUK)

**DIMENSIONS** in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**



Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А